

SOT-23 Plastic-Encapsulate Transistors

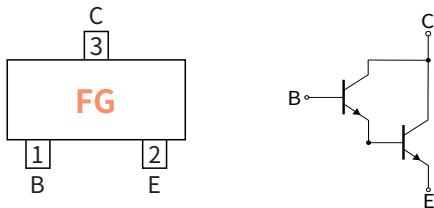
Features

- High Collector Current
- High Current Gian

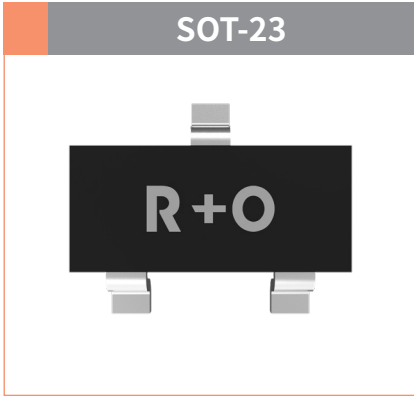
Mechanical Data

- Case: SOT-23
Molding compound meets UL 94V-0 flammability rating, RoHS-compliant,halogen-free
- Terminals: Solder plated, solderable per MIL-STD-750,Method 2026

Function Diagram



Collector-Emitter Voltage
VCEO 60V
Collector Current
0.5 Ampere



Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-23	R1	0.008	3000	15000	150000	7"

Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Collector-Base Voltage	V _{CBO}	V	80
Collector-Emitter Voltage	V _{CEO}		60
Emitter-Base Voltage	V _{EBO}		10
Collector Current	I _C	mA	500
Collector Power Dissipation	P _C	mW	300
Storage temperature	T _{stg}	°C	-55 ~+150
Junction temperature	T _j	°C	-55 ~+150
Typical Thermal Resistance	R _{θJA}	°C /W	416

Electrical Characteristics (Ta=25°C Unless otherwise noted)

PARAMETER	SYMBOL	UNIT	Condition	Min	Typ	Max
Collector-Base Breakdown Voltage	V _{(BR)CBO}	V	I _C =100μA, I _E =0	80	—	—
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}		I _C =10mA, I _B =0	60	—	—
Emitter-Base Breakdown Voltage	V _{(BR)EBO}		I _E =10μA, I _C =0	10	—	—
Collector-Base cut-off current	I _{CBO}	μA	V _{CB} =60V, I _E =0	—	—	0.1
Emitter-Base cut-off current	I _{EBO}		V _{EB} =4.0V, I _C =0	—	—	0.1
DC Current Gain	h _{FE}	—	V _{CE} =1.0V, I _C =0.1mA	2000	—	—
			V _{CE} =5.0V, I _C =10mA	4000	—	—
			V _{CE} =5.0V, I _C =100mA	10000	—	—

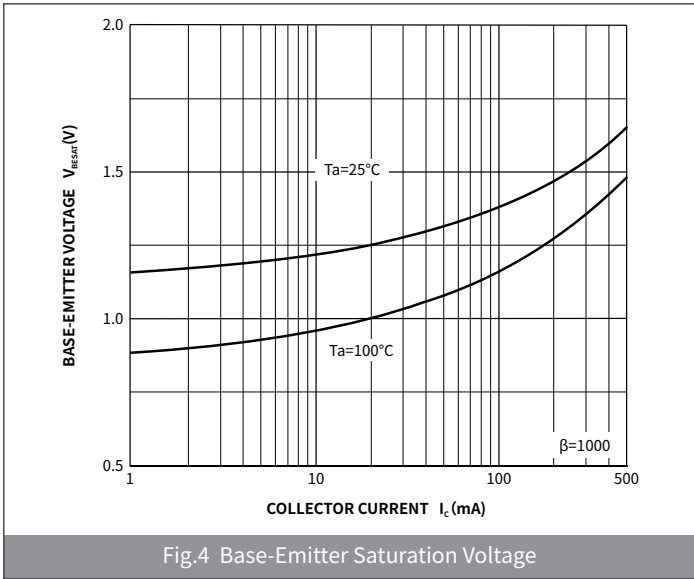
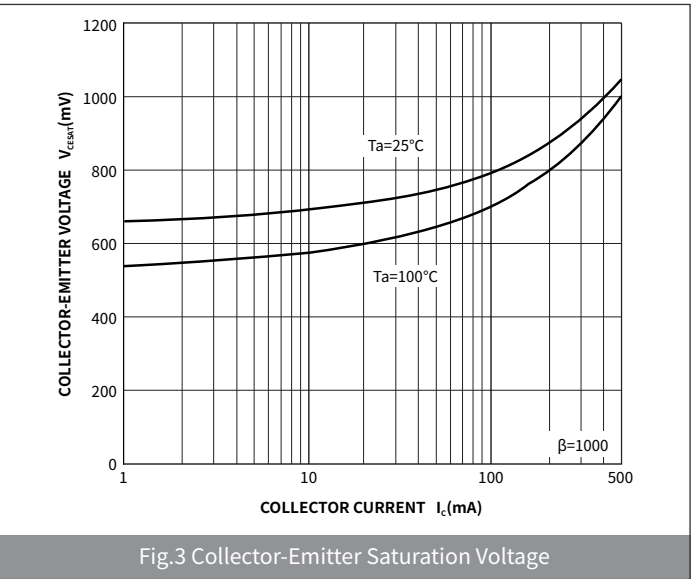
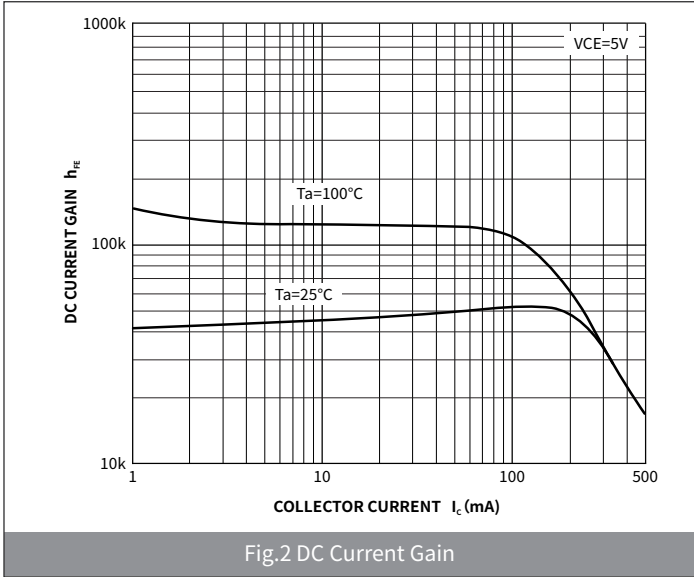
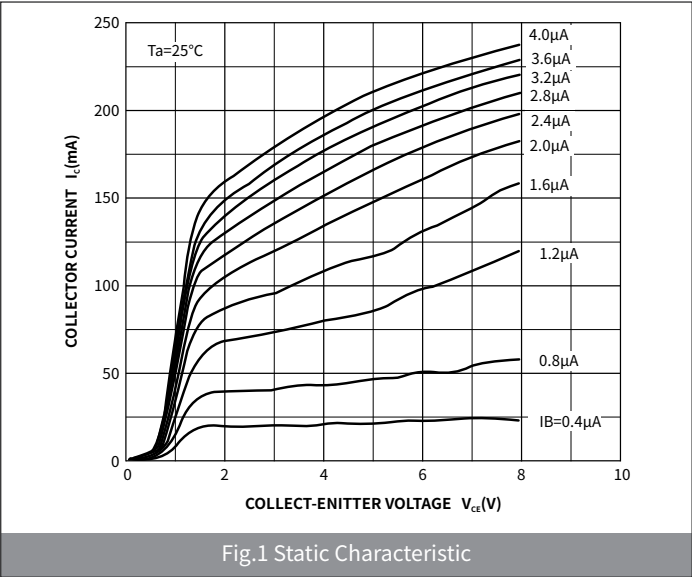
● **Electrical Characteristics** (Ta=25°C Unless otherwise noted)

PARAMETER	SYMBOL	UNIT	Condition	Min	Typ	Max
DC Current Gain	h_{FE}	—	$V_{CE}=5.0V, I_C=500mA$	2000	—	—
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V	$I_C=100mA, I_B=0.1mA$	—	—	1
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	V		—	—	1.5
Output Capacitance	C_{ob}	pF	$V_{CB}=10V, I_E=0, f=1MHz$	—	3.5	—

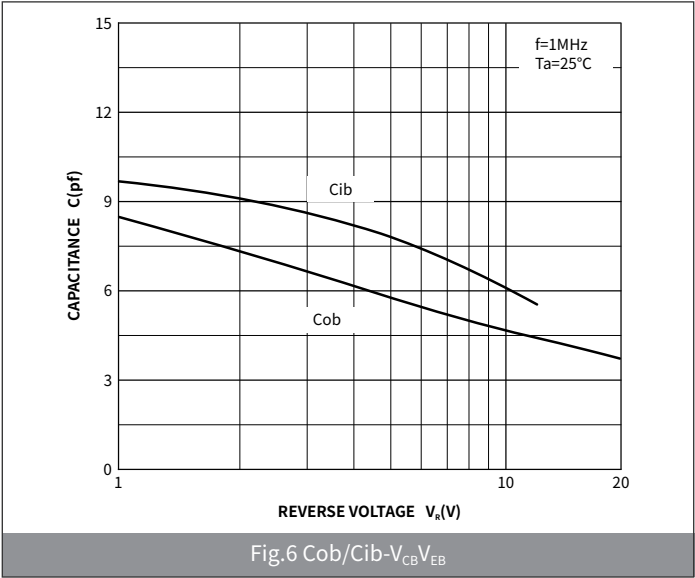
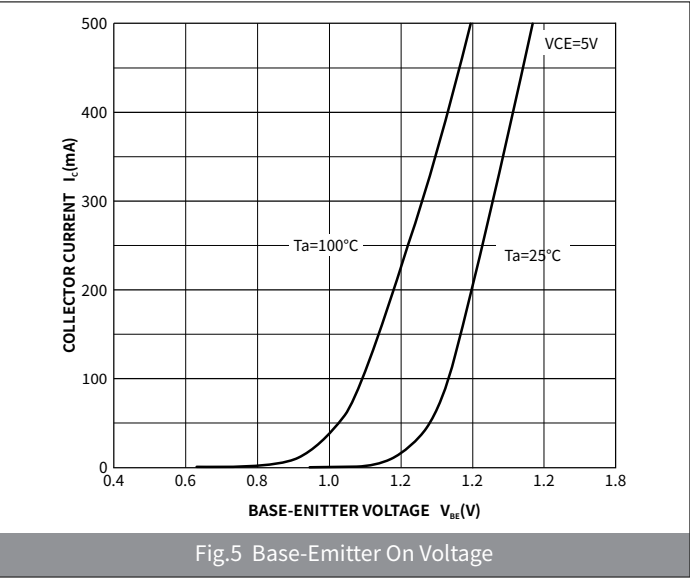
● **Small-signal Characteristics**

ITEM	SYMBOL	Condition	UNIT	Min	Typ	Max
Transition frequency	f_T	$I_C=50mA, V_{CE}=5V$	MHz	—	170	—

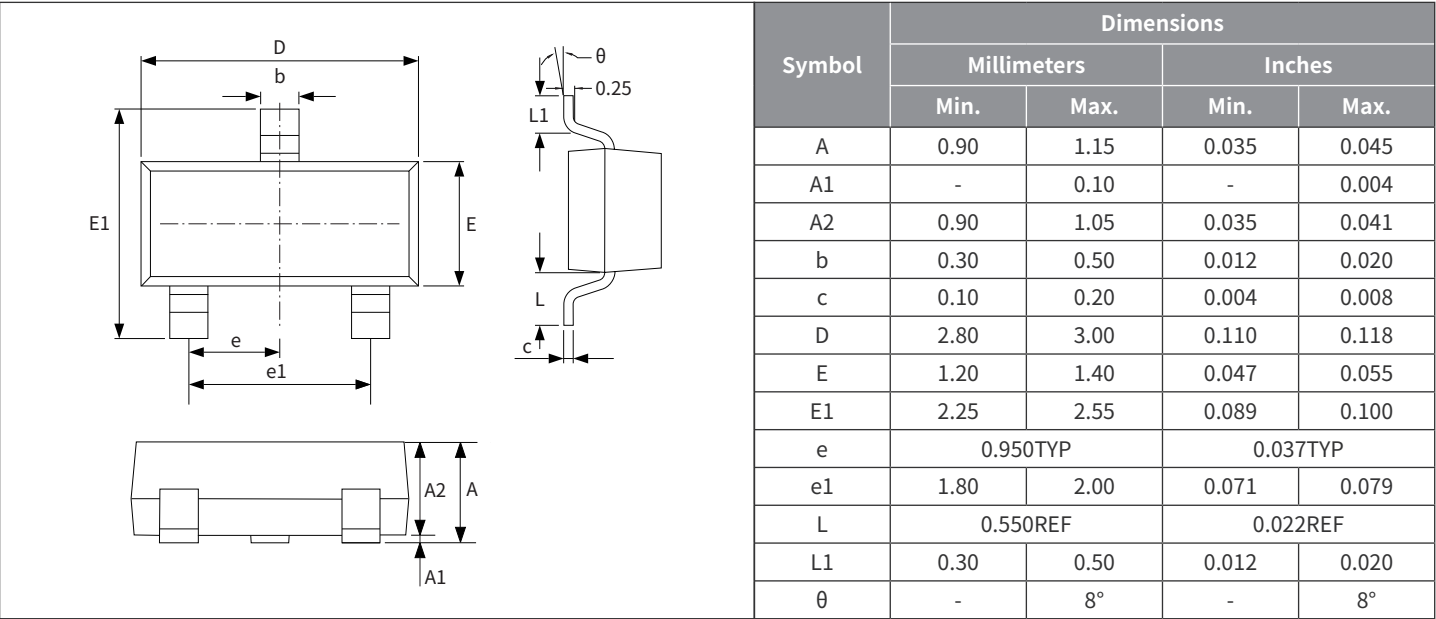
● **Ratings And Characteristics Curves** (Ta=25°C Unless otherwise specified)



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● Package Outline Dimensions (SOT-23)



● Suggested Pad Layout

